# Surface currents and slope selection in crystal growth

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#### A bstract

We face the problem to determ ine the slope dependent current during the epitaxial growth process of a crystal surface. This current is proportional to  $= p_+ p_-$ , where  $p_-$  are the probabilities for an atom landing on a terrace to attach to the ascending  $(p_+)$  or descending  $(p_-)$  step. If the landing probability is spatially uniform, the current is proved to be proportional to the average (signed) distance traveled by an adatom before incorporation in the growing surface. The phenomenon of slope selection is determined by the vanishing of the asymmetry . We apply our results to the case of atoms feeling step edge barriers and downward funnelling, or step edge barriers and steering. In the general case, it is not correct to consider the slope dependent current j as a sum of separate contributions due to diesent mechanisms.

## Resum e

Courants de surface et selection de la pente en croissance cristalline La croissance epitaxiale d'une surface cristalline peut être caracterisse par un courant de surface J, dont la partie j qui depend de la pente est etudise. Celle-ci est proportionnelle  $a=p_+$  p, ou p sont les probabilites qu'un atom e depose sur une terrasse se colle a la marche montante  $(p_+)$  ou descendante  $(p_-)$ . Si la probabilite spatiale d'atterrissage est un iform e, le courant est aussi proportionnel a la distance moyenne (avec signe) parcourue par chaque atom e. Le phenom ene de la selection de la pente est determ ine par la condition =0. Les resultats ainsi obtenus sont appliques aux cas barrière de marche plus downward funnelling et barrière de marche plus braquage (steering). D ans le cas general, le courant j ne peut pas être considere com m e la som m e de contributions separes dues aux di erents mecanism es.

K ey words: Crystal growth; Surface current; Di usion

M ots-cles : C roissance cristalline; C ourant de surface; D i usion

# 1. Introduction

M olecular Beam Epitaxy is a wellknown and widespread technique to growth layers of metal and sem iconductor crystals. The growth process of a high symmetry crystal surface can be described through a ballistic ux of

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particles impinging on the growing surface and the following thermaldiusion of adatoms, which nally attach to a preexistent step or nucleate new terraces [1,2,3].

One crucial aspect of the growth process is its possible unstable character, due to determ inistic mechanisms which prevent the growing surface to remain at. In this paper we focus on mound formation and we will discuss its description via a mesoscopic surface current J, which enters in the evolution equation  $\ell_t z = F t - \ell_x J$ , where F is the ux of incoming particles and z is the local height. Experiments show that dynamics can produce coarsening, with the formation of mound facets of constant slope m [4].

In the theoretical sem inal papers [5,6] the cause for mound form ation was identified in the existence of step edge barriers, i.e. an additional barrier hindering the descent of steps. Since then, many e orts [2] have been devoted to the form alization of this idea and to the derivation of quantitative predictions for the evolution of mounds. These e orts have often combined phenomenological approaches with attempts of a rigorous derivation of J starting from the microscopic dynamics of adatons.

The main piece of the current J is the so called slope dependent current j(m), depending on the local slope m of the surface. J also contains terms depending on higher order derivates, but the rising of the instability and the possible formation of mounds with a constant slope m only depend on j(m). Therefore, it is natural that special attention has been devoted to its determination. A nalytical approaches have followed two mainstreams: coarse-graining procedures [7,8,9] to pass from step-dynamics to mesoscopic dynamics (see next Section) and the evaluation of j(m) through the average (signed) distance [10,11] walked by adatoms before being incorporated in the growing crystal (see Section 5).

A recent paper by Li and E vans [12] has renewed the interest on the slope dependent current. A uthors claim ed that standard phenom enological continuum theories are inappropriate to describe m ound slope selection. A fterwards some of their claims have been corrected [13], but their work has shown that j(m) should be evaluated with great care. For these reasons, in the following we reconsider the problem, giving a formulation as general as possible for the slope dependent current and for the evaluation of the selected slope m, determined by the condition j(m) = 0. We prove that the current j(m) is proportional to the asymmetry (L) =  $p_+$  (L)  $p_-$  (L) between the probabilities for an atom deposited on a terrace of size L to be incorporated into the upper ( $p_+$ ) and lower ( $p_-$ ) steps. This proof does not refer to any speci c m icroscopic m echanism. An important by-product is that, in general, j(m) can not be considered as a sum of contributions due to separate m echanisms. Finally, we also discuss the alternative formulation for the current in terms of the averaged (signed) distance walked by adatoms before incorporation.

#### 2. The current

In the case of conserved growth (no desorption, no overhangs), a useful concept to study the dynam ics of the surface is the mesoscopic current J, entering via the evolution equation  $\theta_t z = Ft - \theta_x J$  for the local height z. It is worth stressing that the dynam ics of the surface, and therefore the current J, are determined by the dynam ics of steps: adatom s enter only through their attachment (and detachment) rate to steps.

A piece of surface of slope m looks di erently, according to the value of the slope. For large m (Fig. 1a) we have a sequence of all uphill or downhill terraces of size L  $^\prime$  1=jm j. For sm all m (Fig. 1b) we have a mix of di erent types of terraces of size L  $^\prime$  b, where b is the nucleation length [2]: in this case, the average slope is determined by uncompensated uphill and downhill terraces. The two pieces of surface look di erently because nucleation on terraces prevent them being larger than being large

The analytical determ ination of the current J starts from the large slope case (see Fig. 1a). In a one dimensional picture, the ux FL of atoms landing on the terrace splits in two currents j (L) = FLp (L), where p (L) are the probabilities that an atom attaches to the ascending (p+) or descending (p) step. The velocity of the n th step is simply equal to [j ( $L_{n+1}$ ) + j+ ( $L_n$ )]. The sum (p+ + p) = 1, while = (p+ p) denotes the asymmetry

Following the method introduced in Ref. [7], the displacement of step n during the deposition of one monolayer can be approximated as

$$x_n (t+ 1=F) x_n (t) = \frac{1}{F} [j (L^0) + j (L^0)];$$
 (1)

where  $L^0 = \frac{1}{2}(L_n + L_{n-1})$  and  $L^0 = \frac{1}{2}(L_n + L_{n+1})$ . It is useful to sum the quantity  $L_n$  to both sides, so as to have

$$x_n (t + 1 = F) x_n (t) + L_n = \frac{1}{2} [L^{0} + L^{0} 2L_n + L^{0} (L^{0}) L^{0} (L^{0})];$$
 (2)

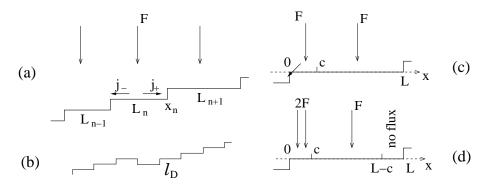


Figure 1. (a,b) Schem atic of a growing one dimensional surface at (a) large and (b) small slope (gure b has been shrinked). (c,d) Coordinates for the models studied in Section 3: (c) Downward Funnelling and Ehrlich-Schwoebele ect; (d) steering and Ehrlich-Schwoebele ect.

The quantity on the left can be approximated as ( 1=m F) $\theta_t z = (1=m F)\theta_x J$ , where m=1=L is the slope. The quantity on the right can be worked out using the relations [7,14]

$$L^{00} + L^{0} 2L_{n} \frac{1}{2} L^{2} \theta_{xx} L + L (\theta_{x} L)^{2}$$
 (3)

$$L^{\circ} (L^{\circ}) L^{\infty} (L^{\infty}) (L^{\circ} L^{\infty}) @_{L} [L (L)] L @_{x} L @_{L} [L (L)];$$

$$(4)$$

Finally, we get

$$\frac{1}{m F} e_x J = \frac{1}{m} e_x \qquad \frac{L e_x L}{4} + \frac{L (L)}{2} ; \qquad (5)$$

so that the total current J com es out to be

$$J = \frac{1}{2}FL (L) \frac{1}{4}FL@_{x}L:$$
 (6)

If we use the slope m , the second term takes the form  $\frac{1}{4}F$  ( $\theta_x m$ )=m  $^3$ , which was already found in Refs. [7,8]. In the following we will focus on the slope dependent part,

$$j = \frac{1}{2} F L \quad (L):$$
 (7)

We estress that Eq. (7) is the most general form, not depending on any assumption on the miscroscopic processes occurring at the surface. It is valid for large slope,  $m>1=\boldsymbol{'}_D$  (Fig. 1a). In the opposite limit,  $m<1=\boldsymbol{'}_D$  (Fig. 1b), j(m) is linear [7] in m, as also expected from symmetry reasons for a slope dependent current: j(m) = j(1=\boldsymbol{'}\_D)\boldsymbol{'}\_D m, where j(1=\boldsymbol{'}\_D) = \frac{1}{2}F\boldsymbol{'}\_D (\boldsymbol{'}\_D) is evaluated according to (7).

The condition of instability of the at surface reads  $j^0(0) > 0$ , i.e.  $j(1={}^{t_D}) > 0$ , as trivially shown by a linear stability analysis [15]. Finally, if m ounds develop facets with constant slope m , the current must vanish on it: j(m) = 0.

### 3. Downward funnelling, step edge barriers and steering

Let us now consider the following model (see Fig. 1c). A tom s deposited within a distance c from the descending step are incorporated in it (downward finnelling, D F), while atoms deposited in the remaining (L c) portion of the terrace discuss freely, feeling an additional (Ehrlich-Schwoebel, ES) barrier at the descending step. A toms deposited in the c region give a trivial contribution F c to j . As for the others, we must solve the discussion equation F + D  $^{00}(x) = 0$  for c < x < L and  $^{00}(x) = 0$  for 0 < x < c, with boundary conditions  $^{0}(0) = (0) = ^{1}_{ES}$ , (L) = 0, and (x);  $^{0}(x)$  continuous in x = c. The quantity  $^{1}_{ES} = 0$  is the well known Ehrlich-Schwoebel length and measures the additional barrier felt by an adatom in the sticking process to the descending step. It is straightforward to get

$${}^{0}(0) = \frac{F}{2D} \frac{(L c)^{2}}{L + r}; \qquad {}^{0}(L) = \frac{F}{2D} \frac{(L c)(L + c + 2r_{ES})}{L + r_{ES}}; \qquad (8)$$

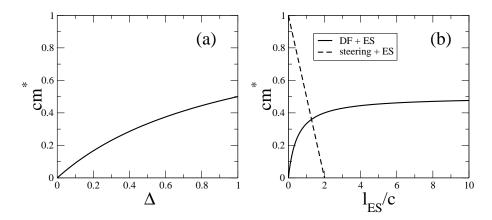


Figure 2. (a) The selected slope cm as a function of 'Esset (12-13). (b) Full line: the selected slope cm as a function of 'Esset (DF+ES model, Eq. (14)). Dashed line: the slope m such that j (m ) = 0 for the steering+ES model (Section 3). There is no slope selection in this case, because  $j^0$  (m ) > 0.

The contributions of atom s deposited in the (L  $\,$  c) region to the currents j  $\,$  are D j  $^{0}$  (L) j and D  $^{0}$  (0), respectively. Therefore

$$j = F c + \frac{F}{2} \frac{(L - c)^2}{L + \frac{1}{2} c} \quad F L p \quad (L); \quad j_+ = \frac{F}{2} \frac{(L - c) (L + c + 2 \frac{1}{2} c)}{L + \frac{1}{2} c} \quad F L p_+ \quad (L);$$
 (9)

Their sum gives the total ux of particles arriving on the terrace:  $j_+ + j_- = FL$ , while their (sem i-)di erence gives the current  $j = \frac{1}{2}FL$  (L) =  $\frac{1}{2}(j_+ - j_-)$ , i.e.

$$j = \frac{F}{2} \frac{{}^{\backprime}_{ES} (L - 2c)}{L + {}^{\backprime}_{ES}} = \frac{F}{2} \frac{{}^{\backprime}_{ES} (1 - 2mc) - mc^2}{1 + m {}^{\backprime}_{ES}};$$
 (10)

If c = 0, we not the well known result  $j = \frac{1}{2}FL'_{ES} = (L + '_{ES}) = \frac{1}{2}F'_{ES} = (1 + m'_{ES})$ .

Eq. (10) shows that it is not generally possible to write j as a sum of two separate contributions,  $j=j_{ES}+j_{DF}$ , due to the Ehrlich-Schwoebel (ES) elect and to the downward funnelling (DF), respectively. In fact, it is instructive to consider the two limits  $Y_{ES}=0$  and  $Y_{ES}=1$ . For  $Y_{ES}=1$ ,  $Y_{ES}=1$ 

Let us now consider a situation where the ux of particles on the terrace is not uniform, see Fig. 1d. Because of steering e ects [16], we assume that all atoms destined to land within distance c from the ascending step are steered and nally land in the cregion close to the descending step (of the upper terrace). So, this region undergoes an elective ux 2F. W orking out calculations [17] similar to those made here above, we get the result

$$j = \frac{F}{2} \frac{{}^{\backprime}_{ESL} 2c(L c)}{L + {}^{\backprime}_{ES}} = \frac{F}{2} \frac{2c^2m + {}^{\backprime}_{ES}}{1 + m {}^{\backprime}_{ES}} :$$
 (11)

This current is always positive if  ${}^{\backprime}_{ES} > 2c$ , or it changes sign in  $m = (1 \quad {}^{\backprime}_{ES} = 2c) = c$ , if  ${}^{\backprime}_{ES} < 2c$  (see Fig. 2b, dashed line). However, in the latter case  $j^0$  (m ) > 0, which implies instability of the slope m [18]. So, in this model there is no slope selection: either the surface is always unstable or it is metastable [19].

# 4. Slope selection

First, let us apply the condition j (m) = 0 to a model studied by Li and Evans [12]:

$$j_{+} = F (L c)P_{+}; \quad j_{-} = F c + F (L c)P_{-};$$
 (12)

If P are the probabilities for atom s deposited in the (L  $\,$  c) region to attach to the step, this m odel is sim ilar to what we studied in the previous Section . For constant P , the condition  $j_{+}=j$  , i.e. =0, gives the following expression for the selected slope m ,

$$m = \frac{1}{c(1+c)};$$

where  $= P_+ P_-$  . Note that is not the total asymmetry , which vanishes for  $m = m_-$ , but the asymmetry for atoms deposited in the (L c) portion of the terrace only. In Fig. 2a we report cm (). Eq. (13) perfectly matches the numerical results given in [12].

Let us now turn back to Eq. (10). In this case, we get

$$m = \frac{{}^{\prime}_{ES}}{c(c+2{}^{\prime}_{ES})}:$$
 (14)

In Fig. 2b (full line) we plot on as a function of  ${}^{\backprime}_{ES}$  =c. For small and large  ${}^{\backprime}_{ES}$  =c,  $m = {}^{\backprime}_{ES}$  =c<sup>2</sup> and m = 1 = (2c), respectively. Therefore, for large ES barrier the selected slope corresponds to a terrace size equal to 2c, as expected by a trivial compensation of DF and ES expected.

The use of (10), as well as of (12), to nd m is limited by the constraint m > 1='b. For Eq. (10) this means  $'E_S > c^2 = 'b$ . For Eq. (10) this means  $'E_S > c^2 = 'b$ , in the opposite limit,  $'E_S < c^2 = 'b$ , j(1='b) < 0 and no selected slope exists: this happens because the DF e ect is so strong to induce a stabilizing (downhill) current at all slopes.

#### 5. A nother expression for the current

The expression  $j(L) = \frac{1}{2}FL$  (L) is the most general one for the slope dependent current on a region of (large) slope m = 1 = L. The quantity (L) = (p<sub>1</sub> p) measures the asymmetry between the sticking probabilities to the upper and lower steps. The ux F is usually assumed to be spatially uniform, apart from uctuations. However, as anticipated in the previous Section, because of atom-substrate interactions, steering elects may occur and atoms are no more deposited uniformly on the terrace. In spite of this, the expression  $j(L) = \frac{1}{2}FL$  (L) still continues to be correct. In the Introduction we mentioned a possible different evaluation of j(m), through the average signed distance dwalked by an adatom, from the deposition to the incorporation site. In the following we are proving the equivalence of the two expressions, if the ux is uniform. If it is not uniform, the average distance d is not an appropriate quantity to determine j.

The convention is to take d positive if the atom attaches to the ascending step (see Fig. 1):

$$d = \frac{1}{L} \int_{0}^{ZL} dx [(L \quad x)p_{+} (x) \quad xp_{-} (x)] = \int_{0}^{ZL} dx p_{+} (x) \quad \frac{1}{L} \int_{0}^{ZL} dx (p_{+} (x) + p_{-} (x))x;$$
 (15)

with p (x) being the probabilities that an adatom deposited in x attaches in x=0 (p (x)) and in x=L (p, (x)). Since  $p=(1=L)_0^R dxp$  (x) and (p, (x)+p (x))=1, we get  $d=Lp_+$   $\frac{1}{2}L=\frac{1}{2}L$  (L), so that

$$j(L) = \frac{1}{2}FL \quad (L) = Fd$$
: (16)

In a K inetic M onte C arlo simulation, we can easily implement the above expression and write

$$j_{\rm KMC} = F \frac{N_{\rm r} N_{\rm l}}{N_{\rm a}}$$
 (17)

where  $N_{r;l}$  are the total hops in the uphill and downhill direction, and  $N_a$  is the total number of deposited atoms. Formula (17) was rstly introduced in Ref. [10] and has the merit to be valid for a surface of any slope. At author's knowledge, a rigorous derivation and a comparison with the mesoscopic current were missing.

It is worth stressing that Eqs. (16-17) are no m ore applicable if the landing probability is not spatially uniform . In this case, j(L) is no m ore proportional to d, as shown by a trivial example: no downward funnelling (c = 0) and in nite ES barrier,  ${}^{`}_{ES} = 1$ . The resulting current  $j = \frac{1}{2}FL$  can be written as j = Fd if the ux is uniform: in that case,  $d = \frac{1}{2}L.D$  i erent spatial distributions of the landing atom s modify d and therefore the expression j = Fd, but do not modify the correct expression  $j = \frac{1}{2}FL$ , because the step dynamics would be unchaged.

#### 6. Final remarks

In this paper we mainly focused on the slope dependent current and the slope selection mechanism. We have shown that a correct derivation of this current is possible and its general expression has been found. The condition j(m) = 0 determines the selected slope. More generally, the shape  $z_s(x)$  (or  $m_s(x) = z_s^0(x)$ ) of stationary solutions depends on the vanishing of the full current J in all the points,  $J(m_s(x)) = 0$ . It is worthnoting that the conditions j(m) = 0 and  $J(m_s(x)) = 0$ , when applied to a discrete or discrete-continuous model, are valid only averaging J on time scales not smaller than 1=F [12].

With regard to additional terms in the current, our derivation in Section 2 shows that a symmetry breaking term, having the form  $J = \theta_x A \text{ (m}^2)$ , appears naturally when we coarsen step dynamics. This term is the only term surviving in a plain vicinal surface without any additional microscopic mechanism (no step edge barriers, no nucleation, no thermal detachment, no downward funnelling): so, in this sense, it should be considered the most fundamental one. Finally, J should also contain at least a Mullins-like term, J  $\theta_{xx}$ m, which may be due to several mechanisms [20].

However, even if the rigour in the derivation of the mesoscopic current has improved in the course of time, the evolution equation  $\theta_t z = Ft$  r j is not much more than a phenomenological equation, specially in two dimensions where additional problems linked to step edge di usion exist. The dynamics of a truly vicinal surface, which can be studied with much more rigour [21], shows that the full nonlinear equations governing the growth process of a real system are far more complicated.

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